

CMOS 8-Channel **Data Selector**

High-Voltage Types (20-Volt Rating)

CD4512B is an 8-channel data selector featuring a three-state output that can interface directly with, and drive, data lines of bus-oriented systems.

The CD4512B-series types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

Features:

- 3-state output
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- 5-V, 10-V, and 15-V parametric ratings
- Maximum input current of 1 µA at 18 V over full packagetemperature range; 100 nA at 18 V and 25°C

Noise margin (over full package-temperature range): $1 \text{ V at V}_{DD} = 5 \text{ V}$ 2 V at V_{DD} = 10 V

2.5 V at V_{DD} = 15 V

v

Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

- Digital multiplexing
- Number-sequence generation

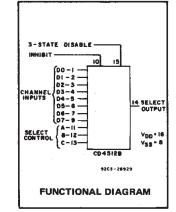
RECOMMENDED

Supply-Voltage Range (For TA = Full Package

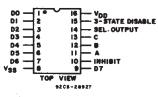
For maximum reliat operation is always

	Signal gating	j		
DED OPERATING CONDITIONS reliability, nominal operating con ways within the following ranges:	nditions should be	selected so the	t	
	LIN	AITS	UNITS	
CHARACTERISTIC	MIN.	MAX.	UNITS	

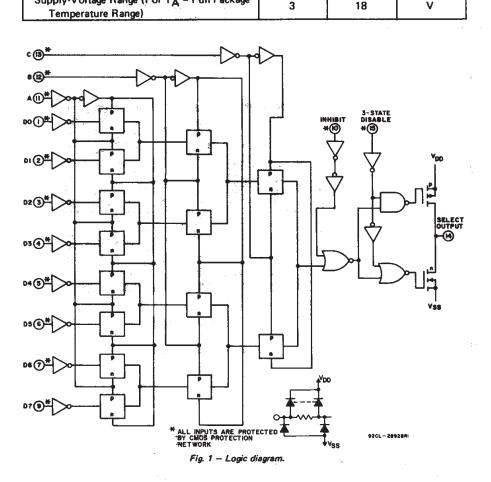
3



CD4512B Types



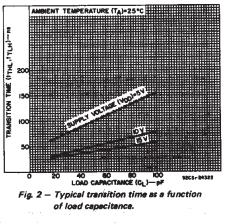
TERMINAL ASSIGNMENT



TRUTH TABLE SEL. CONT. 3-STATE SEL INH A В С DISABLE OUTPUT 0 0 0 0 D0 0 0 0 0 0 D1 1 0 0 1 0 0 D2 1 1 0 0 0 D3 0 0 1 0 0 **D4** 0 1 0 0 **D**5 1 0 1 1 0 0 **D6** 1 1 1 0 0 D7 х х Х 1 0 0 х Х х X 1 High Z

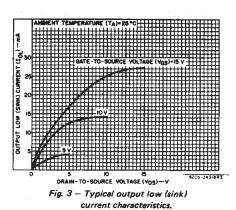
= High Level 0 = Low Level

X = Don't Care



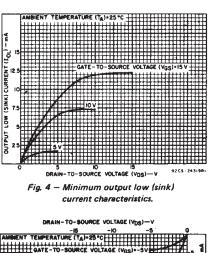
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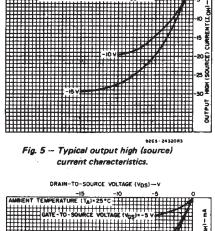
MAXIMUM RATINGS, Absolute-Maximum Values:	
DC SUPPLY-VOLTAGE RANGE, (VDD)	
Voltages referenced to VSS Terminal)	-0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS	
DC INPUT CURRENT, ANY ONE INPUT	
POWER DISSIPATION PER PACKAGE (PD):	Э
For $T_A = -55^{\circ}C$ to $+100^{\circ}C$	
For $T_A = +100^{\circ}C$ to $+125^{\circ}C$	Derate Linearity at 12mW/ ⁰ C to 200mW
For T _A = +100°C to +125°C DEVICE DISSIPATION PER OUTPUT TRANSISTOR	Derate Linearity at 12mW/ ^O C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
DEVICE DISSIPATION PER OUTPUT TRANSISTOR FOR T _A = FULL PACKAGE-TEMPERATURE RANGE (All Package Type	əs)
DEVICE DISSIPATION PER OUTPUT TRANSISTOR FOR T _A = FULL PACKAGE-TEMPERATURE RANGE (All Package Type OPERATING-TEMPERATURE RANGE (T _A)	es)
DEVICE DISSIPATION PER OUTPUT TRANSISTOR FOR T _A = FULL PACKAGE-TEMPERATURE RANGE (All Package Type	es)

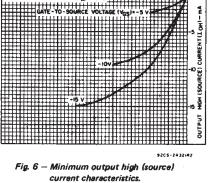


STATIC ELECTRICAL CHARACTERISTICS

CHARAC- TERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (^O C)								
	Vo (V)	V _{IN}	V _{DD} (V)	-55 -40 +85 +125				Min.	+25 Typ.	Max.	S	
	_	0,5	5	5	5	150	150	_	0.04	5		
Quiescent Device	_	0,10	10	10	10	300	300	-	0.04	10		
Current,		0,15	15	20	20	600	600	-	0.04	20	μA	
I _{DD} Max.	_	0,20	20	100	100	3000	3000		0.08	100		
Output Low	0.4	. 0,5	5	0.64	0.61	0.42	0.36	0.51	1	-		
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	_		
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	-		
Output High	4.6	0,5	5	-0.64	0.61	-0.42	-0.36	-0.51	-1	_	mA	
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-		
Current, I _{OH} Min.	9.5	0,10	10	. –1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-		
'OH WITT	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	—		
Output Voltage:	_	0,5	5		0.	05	_	0	0.05			
Low-Level,	—	0,10	10		0.	05	_	0	0.05			
VOL Max.	-	0,15	15		0.	05	_	0	0.05	v		
Output	_	0,5	5		4.	95		4,95	5			
Voltage: High-Level,	-	0,10	10		9	95		9.95	10	-		
V _{OH} Min.	-	0,15	15	A	14	95		14.95	15	<u>_</u>		
Input Low	0.5,4.5	1	5			1.5				1.5		
Voltage	1,9	-	10			3		·	·	3		
V _{IL} Max.	1.5,13.5	-	15			4	1.1.1	-	-	4	v	
Input High	0.5,4.5	-	5			3.5	-	-				
Voltage,	1,9	-	10			7		7	and a second s	-	-	
V _{IH} Min.	1.5,13.5	-	15		5. 2	11		11		·*		
Input Current ¹ IN Max.	_	0,18 ·	18	±0.1	±0.1	‡1	±1		±10 ⁻⁵	±0.1	μА	
3-State Output Leakage Current I _{OUT} Max.	0,18	0,18	18	±0.4	±0.4	±12	±12		±10 ⁻⁴	±0.4	μΑ	



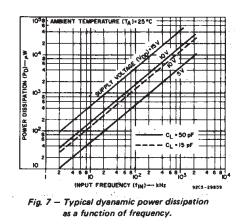




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DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}$ C, Input $t_r, t_f = 20$ ns, CL = 50 pF, RL = 200 kΩ

CHARACTERISTIC	TEST CONDITIONS	LIN	UNITS	
	V _{DD} (V)	Тур.	Max.	
Propagation Delay Time, tpHL, tpLH Inhibit to Output	5 10 15	140 70 50	280 140 100	
"A" Select to Output	5 10 15	200 85 60	400 170 120	ns
Data to Output	5 10 15	180 75 55	360 150 110	
3-State Disable Delay Time: [†] PZL, [†] PLZ, [†] PHZ, [†] PZH	5 10 15	60 30 20	120 60 40	ns
Transition Time, tTHL, tTLH	5 10 15	100 50 40	200 100 80	ns
Input Capacitance, C _{IN} (Any Input)		5	7.5	p۴



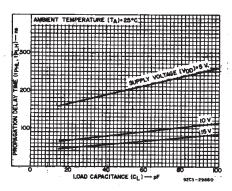
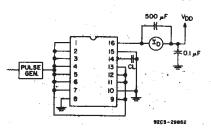


Fig. 8 – Typical propagation dalay time as a function of load capacitance ("A" select to output).



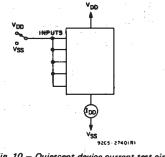
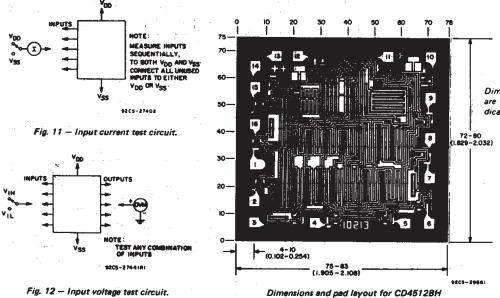


Fig. 9 - Dynamic power dissipation test circuit.

Fig. 10 - Quiescent device current test circuit.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mills (10^{-3} inch).



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CD4512BE	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4512BE	Samples
CD4512BEE4	ACTIVE	PDIP	Ν	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD4512BE	Samples
CD4512BF	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4512BF	Samples
CD4512BF3A	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD4512BF3A	Samples
CD4512BM	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4512BM	Samples
CD4512BM96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4512BM	Samples
CD4512BM96G4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4512BM	Samples
CD4512BMT	ACTIVE	SOIC	D	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4512BM	Samples
CD4512BMTG4	ACTIVE	SOIC	D	16	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4512BM	Samples
CD4512BNSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4512B	Samples
CD4512BPW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM512B	Samples
CD4512BPWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM512B	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.



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PACKAGE OPTION ADDENDUM

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD4512B, CD4512B-MIL :

• Catalog : CD4512B

Military : CD4512B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD4512BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4512BNSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD4512BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

27-Jul-2021



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4512BM96	SOIC	D	16	2500	340.5	336.1	32.0
CD4512BNSR	SO	NS	16	2000	853.0	449.0	35.0
CD4512BPWR	TSSOP	PW	16	2000	853.0	449.0	35.0

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



4211283-4/E 08/12

D (R-PDSO-G16) PLASTIC SMALL OUTLINE Stencil Openings (Note D) Example Board Layout (Note C) –16x0,55 -14x1,27 -14x1,27 16x1,50 5,40 5.40 Example Non Soldermask Defined Pad Example Pad Geometry (See Note C) 0,60 .55 Example 1. Solder Mask Opening (See Note E) -0,07 All Around

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW0016A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0016A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0016A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



^{8.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



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